## INFORMATION DISCLOSURE CITATION IN AN APPLICATION

(Use several sheets if necessary)

113197-020	Atty D	ocket No.
		113197-020

Application No. Unknown

Group

Applicant

Yamamoto, S., et al.

Filing Date
January 14, 2002

Unknown

PTO Form 1449

-		U.S. PA	TENT DOCUMENTS			المالات
Examiner's Initials	Document Number	Publication Date	Inventor	Class	Subclass	Filing Date If Appropriate
Met	3,993,939	11-23-76	Slavin et al.			
Melt	4,092,696	5-30-78	Boesen et al.			
1114	4,823,230	4-18-89	Tiemann			
Mes	4,831,492	5-16-89	Kuisma			
MA	4,838,088	6-13-89	Murakami			
NU	5,186,054	2-16-93	Sekimura			
MI	5,241,864	9-7-93	Addie et al.			
NUS	5,528,452	6-18-96	Ko			
MLA	5,585,311	12-17-96	Ko			
MA	5,591,679	1-7-97	Jakobsen et al.		-	
NIH	5,706,565	1-13-98	Sparks et al.			
MH	5,929,497	7-27-99	Chavan et al.			
MA	5,936,164	8-10-99	Sparks et al.			
Nes	6,109,113	8-29-00	Chavan et al.			

	FOREIGN PATENT DOCUMENTS								
Examiner's	Document	Publication			Translation				
Initials	Number	Date	Country	Class	-Subclass-	-Yes-	No		
NST	11-326095	11-26-99	Japan	_					

Examiner's Initials	OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)
NH	Seidel, H., et al., "Anisotropic Etching of Crystalline Silicon in Alkaline Solutions," J. Electrochem, Soc., Vol. 137, No. 11, November 1990, pp. 3626-3632.
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Examiner:	M	prisse	Lu	Date Considered:	10	//	Z	113

\*Examiner: Initial if citation considered, whether or not citation is in conformance with PEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.